

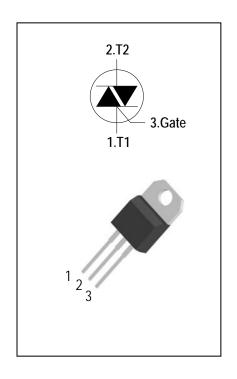
### 3 Quadrants High temperature Triacs

### **General Description**

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The AIT6CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance atgiven junction temperatures.

### **Features**

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 6 A)
- ♦ High Commutation dv/dt
- ◆ Isolated heatsink mounted, Isolation Voltage (Viso = 2500V AC)
- High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



### **Absolute Maximum Ratings**

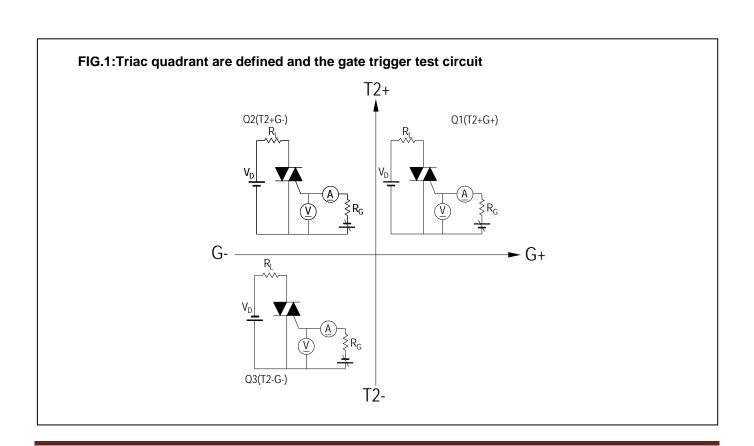
Symbol	Items	Conditions		Ratings	Unit
$V_{DRM}$	Depotitive Deals Off Ctate Valtage	T: - 25°C	AIT6CH60	600	V
$V_{RRM}$	Repetitive Peak Off-State Voltage	Tj = 25°C	AIT6CH80	800	V
I <sub>T(RMS)</sub>	R.M.S On-State Current	T <sub>C</sub> = 110 °C		6	Α
I <sub>TSM</sub>	Surge On-State Current	Tp=20ms(50Hz)/tp=16.7ms(60Hz)		70/74	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	tp=10ms		28	$A^2s$
-11/-14	Critical rate of rise of on-state F = 120 Hz Tj = 150°C		50	A /	
dl/dt	current	I <sub>G</sub> = 2 x I <sub>GT</sub> , tr ≤ 100 ns		50	A/µs
I <sub>GM</sub>	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
$P_GM$	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			5	W
Tj	Operating Junction Temperature			- 40 ~ 150	°C
T <sub>STG</sub>	Storage Temperature			- 40 ~ 150	°C





### **Electrical Characteristics**( Tj = 25°C unless otherwise specified )

Symbol	Items		Conditions		AIT6CH60/80			Unit
					S	Blank	В	
I <sub>DRM</sub>	Peak Forward Reverse Blocking		V <sub>DRM</sub> = V <sub>RRM</sub> , Tj = 25°C		5		uA	
I <sub>RRM</sub>	Current		$V_{DRM} = V_{RRM}$ , $Tj = 150$ °C	Max.	2.7		mA	
V <sub>TM</sub>	Peak On-State Voltage		$I_{TM}$ = 8.5A, $t_p$ = 380 $\mu$ s	Max.	1.5		V	
$V_{GD}$	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		V	
$V_{GT}$	Q1-Q2-Q3	Gate Trigger Voltage	V 40V D 200	Max.	1.5		٧	
I <sub>GT</sub>	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$ , $R_L = 33\Omega$	Max.	10	35	50	mA
I <sub>H</sub>	Q1-Q2-Q3	Holding Current	I <sub>T</sub> = 0.1A	Max.	20	45	60	mA
	Q1-Q3	Latching Current	I <sub>G</sub> = 1.2 I <sub>GT</sub>	Max.	20	50	70	mA
Ι <sub>L</sub>	Q2				35	70	100	
dV/dt	Critical Rate of Rise of Off-State  Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	200	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		$V_D$ =400V Tj = 150°C (dl/dt)c=-2.6A/ms	Min.	1	15	20	V/µs
R <sub>th(j-c)</sub>	Junction to case (AC)			Max.	2.7			°C/W
R <sub>th(j-a</sub> )	Junction to ambient			Max.	60			°C/W



# **ADV**

FIG.2: Maximum on-state power dissipation

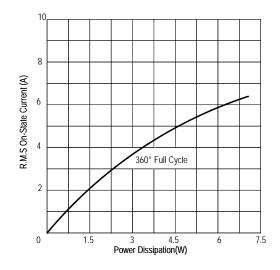


FIG.4: Maximum transient thermal impedance

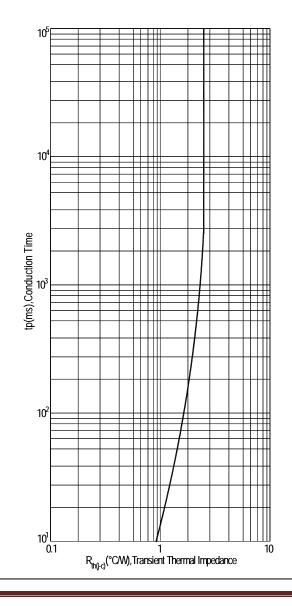


FIG.3: Typical RMS on-state current VS Allowable case Temperature

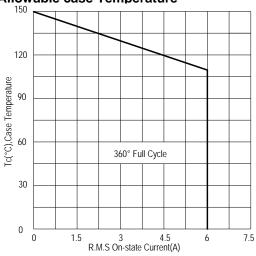


FIG.5: Rated surge on-state current (Non-Repetitive)

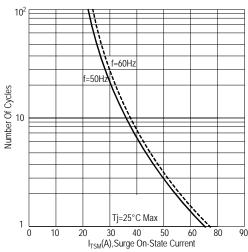


FIG.6: Gate trigger current VS Junction temperature

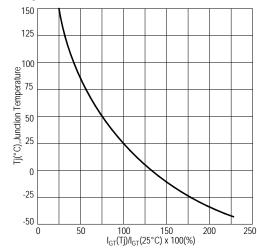




FIG.7:Holding current and Latching current VS Junction temperature

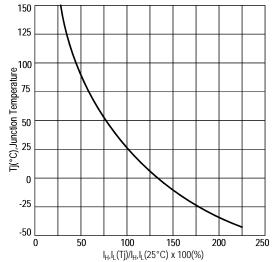
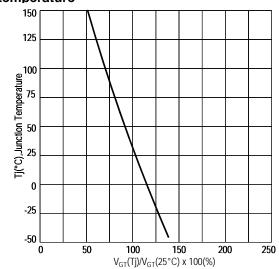
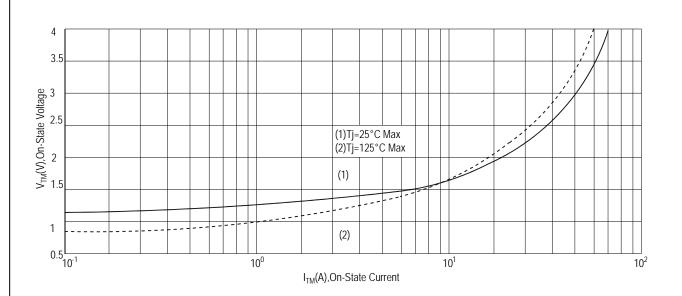


FIG.9: On-state characteristics(Max)

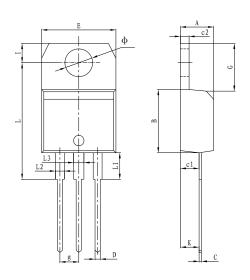
FIG.8: Gate trigger voltage VS Junction temperature





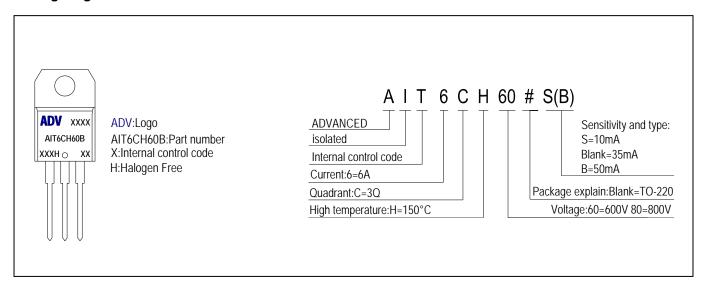


## PACKAGE MECHANICAL DATA TO-220(Isolated) Package Dimension



	Dimer	nsions	Dimensions			
Symbol	In Millimeters		In Inches			
	Min	Max	Min	Max		
Α	4.40	4.60	0.173	0.181		
В	9.00	9.30	0.354	0.366		
С	0.40	0.60	0.015	0.023		
c1	2.00	2.60	0.078	0.102		
c2	c2 1.23		0.048	0.051		
D	0.70	1.00	0.027	0.039		
Е	10.00	10.40	0.393	0.409		
g	2.40	2.70	0.094	0.106		
G	6.20	6.80	0.244	0.267		
I	2.65	2.95	0.104	0.116		
L	L 15.80		0.622	0.661		
L1	3.75		0.147			
L2	1.14	1.70	0.044	0.066		
L3	1.14	1.70	0.044	0.066		
Ф	3.60	3.90	0.141	0.153		
K	2.60TYP		0.102TYP			

### **Making Diagram**



### **Ordering information**

Part number	Part number Package		Packing	Quantity		
AIT6CH60#	TO-220isolated	AIT6CH60#	Tube	50pcs		
AIT6CH80#	TO-220isolated	AIT6CH80#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



### AIT6CH60/80

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